

The challenge of highly curved monolithic imaging detectors



O. Iwert, B. Delabre

ESO, Karl-Schwarzschild-Strasse 2, D-85748 Garching, Germany

ABSTRACT

Current assemblies of image sensors and optics rely on the optics to project a corrected image onto a flat detector surface. In the optical design study of instrumentation for the European Extremely Large Telescope (E-ELT) it was determined that a significant simplification of the optical design - accompanied by an improvement of the image quality - could be achieved through the application of large format (90 mm square) concave curved detectors, with a low radius of curvature (500 - 250 mm). The poster summarizes important developments in the area of curved detectors in the past, their different approaches and ESO's specifications for an on-going feasibility study.

1. NEED A BETTER DETECTOR ? EVOLUTION OF NATURE STILL BEATS TECHNOLOGY

Many features of the human eye have been emulated by detector technology, most of them are routinely used - except the curvature of the retina.

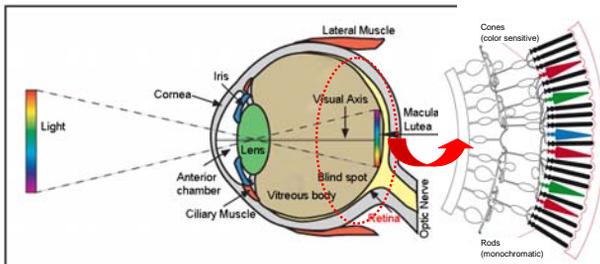


Figure 1: Picture of a human eyeball (left) and detail of its curved retina (right) [1]

2. WHY A CURVED DETECTOR FOR E-ELT ?

Figure 2 shows a typical optical design under study for E-ELT instrumentation - comparing a curved and a flat detector. The correction of the field curvature is a major problem for fast cameras with large field of view. The combination of diverging and converging elements leads to very high incident angles on some optical surfaces. Very often vignetting has to be introduced to limit this effect.

A curved monolithic detector with 90 x 90 mm with curvature radius of 310 mm, would enable to:

- Design a very fast camera of F 1.5 with fewer optical elements, herewith increasing the throughput by ~15 %
- Eliminate the vignetting and optimize the image quality through fewer optical elements and fewer air / glass surfaces
- Eliminate field flattening elements, necessitating to introduce other lenses for their correction
- Introduce cost savings on the optics side

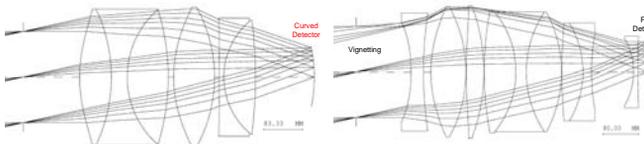


Figure 2: Comparison of optical design with curved detector (left) and flat detector (right) and optical characteristics (below)

Optical characteristics (both cameras)	
Focal length: 300 mm	F/Number: 1.50
Entrance pupil diameter: 200 mm	Entrance pupil location: 125 mm in front of 1st lens
Angular field of view: 25 °	Detector: up to 100 x 100 mm

With a flat detector often NO camera design with an affordable number of lenses can be found with identical transmission and identical field of view.

3. PUBLISHED TECHNIQUES FOR CURVED DETECTORS FILL FACTOR << 100 %:

- Rogers et al [2] developed a CMOS detector (silicon) on a curved rubber substrate, mainly for applications of artificial seeing (figure 3).
- Several mosaics of CCDs have been assembled on a curved substrate (figure 4).



Figure 3: (Top left) Curved CMOS detector on a curved rubber substrate, with optics; (Top right) Individual pixel cells (silicon) on curved rubber substrate; (Bottom) Magnified view of deformable ribbon metal cables between silicon islands

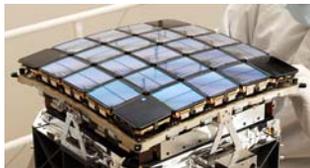


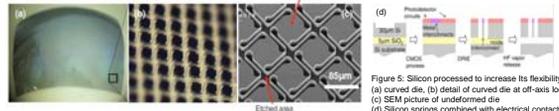
Figure 4: Image of Kepler focal plane, employing a CCD detector mosaic on a curved spherical substrate [3]

4. PUBLISHED TECHNIQUES FOR CURVED DETECTORS FILL FACTOR 100 % : Curving silicon, processing silicon

Jin [4] & Buchhoeft [5] describe techniques to first curve the silicon on a spherically curved glass substrate and then deposit the imager structures via soft lithography. To date no results of this approach are known to produce a working test imager with fill factor 100%.

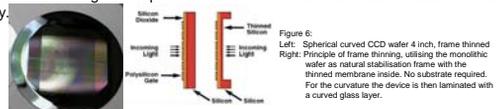
5. PUBLISHED TECHNIQUES FOR CURVED DETECTORS FILL FACTOR = 100 % : Flat silicon processing, thinning, curving

I. Rim & Peumanns [6],[7] (figure 5): The silicon is structured such as to introduce silicon springs between individual pixels islands, increasing its flexibility. Due to these structures this technology is better suitable for backside illuminated CMOS detectors. Curved silicon (without detector) has been produced with size 1cm x 1cm and curvature radius 1cm.



All following techniques deposit first a CCD on flat silicon, then thin it with different backside thinning technologies in order to curve it :

II. Sarnoff process [8]: Figure 6 shows frame thinning at wafer scale without substrate, then bending the center 10..30 μm membrane. Advantages: Handling through monolithic frame, stressfree wet etching. The produced device with curvature radius ~ 500 mm was DC tested only.



III. Lesser process [9]: Figure 7 shows the basic thinning sequence used by M. Lesser. A keypoint for curving the device is the optimum thickness of the substrate supported device.

Main Backside Process Steps, IITL, University of Arizona	
1. Wafer backside grind (vendor)	7. Acid protection
2. Stud bump application	8. Selective acid etch
3. Dice	9. Epitaxial acid etch
4. Hybridize with substrate wafer	10. Oxidize back surface
5. Epoxy underfill	11. Chemispray/AR coating

Figure 7: Backside Process steps at IITL, University of Arizona

IV. JPL process [10]:

- Curved test devices (mainly cylindrical) have been produced:
- Standard silicon:
 - Similar to the Lesser process, but: using a removable substrate, enabling to handle & curve the unsupported detector membrane, applying JPL MBE delta doping process.
 - Thick fully depleted silicon:
 - Polishing the thick wafer into curved shape from backside, JPL MBE delta doping.

6. ESO'S SPECIFICATION & FEASIBILITY STUDY

- ESO has a long term interest in curved large monolithic detectors for E-ELT.
- ESO's specification for curved detectors aims at 90 mm x 90 mm size.
- It concentrates currently onto a feasibility study.
- The latter leaves freedom for demonstration samples of smaller size, but focuses onto the final radius of curvature between 500 and 250 mm (figure 8).

Figure 8: Curved model of 90 x 90 mm detector with curvature radius 500 mm (left), respectively 250 mm (right)

7. STATUS / NEXT STEPS OF ESO FEASIBILITY STUDY

- Simulation of spectral extraction shows a good match between flat & curved detectors.
- August 09: Draft Specification was sent out to a wide variety of companies and research institutions
- Ongoing: Informal discussions with potential partners to define feasibility of study / scope of work and ROM cost per phase
- Q4/2009 Update of specifications, Q1/2010 Formal call for tender procedure

8. IS IT FEASIBLE ? : OPEN ITEMS...

- Is an existing detector construction feasible for curving ?
- How well will an existing detector perform after bending (fields, shift charge, noise...)?
- Will the optical PSF be as before ?
- Which features will the crystal structure exhibit after bending (increased dark current / defects) ?
- What is the most promising approach to curve thinned silicon (supported / unsupported) ?
- What is the optimum thickness before curving the (thinned) detector ?
- Is backside thinning really a requirement for curved silicon ?
- How well is the curving process scaleable after testing small samples (at identical radius of curvature) ?

9. CONTACT

Olaf Iwert, ESO, oiwert@eso.org, office 338, phone +49 / 89 / 320 06 353

10. REFERENCES

- 1) <http://www.studentenlabor.de/seminar/1P/Photorezeptoren.htm>
- 2) John Rogers, University of Illinois, Urbana Champaign, Nature, August 2008
- 3) Ball Aerospace <http://www.ballaerospace.com/jplwv/index.html>
- 4) H. C. Jin, J. R. Abelton, M. Erhardt, R. Nuzzo, "Soft lithographic fabrication of an image sensor array on a curved substrate", Journal of vacuum science and technology 22, 2004
- 5) P. Buchhoeft, M. Calum and B. Choi et al. "Thinning curved surfaces: Template generation by ion beam proximity lithography and relief transfer by step and flash imprint lithography", Journal of vacuum science and technology 17, 1999
- 6) Rostam Driyani, Seung Bum Kim, Kevin Huang, Peter B. Cayless, Peter Peumanns, "Curving monolithic silicon for nonplanar focal plane array applications" Applied Physics Letter 92, 2008
- 7) Seung Bum Kim, Peter B. Cayless, Rostam Driyani, Kevin Huang, and Peter Peumanns, "The optical advantages of curved focal plane arrays", Optics Express, Vol. 16, Issue 17, pp. 4965-4971 (2008)
- 8) P. K. Sear, D. J. Charney, G. C. Taylor, S. A. Lipp and D. S. Mark, "Curved CCDs and their application with astronomical telescopes and stereo panoramic cameras", Proc. SPIE 5301, 109-129 (2004)
- 9) M. Lesser, ISV Symposium on Backside Illumination of Solid-State Image Sensors, 2009 Bergen, Norway & private communication
- 10) S. Nkzad, ISV Symposium on Backside Illumination of Solid-State Image Sensors, 2009 Bergen, Norway & private communication